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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	PIC
Core Size	16-Bit
Speed	70 MIPs
Connectivity	I ² C, IrDA, LINbus, QEI, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, Motor Control PWM, POR, PWM, WDT
Number of I/O	21
Program Memory Size	256КВ (85.5К х 24)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 16
Voltage - Supply (Vcc/Vdd)	3V ~ 3.6V
Data Converters	A/D 6x10b/12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Through Hole
Package / Case	28-DIP (0.300", 7.62mm)
Supplier Device Package	28-SPDIP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic24ep256mc202-i-sp

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Pin Diagrams (Continued)



Pin Diagrams (Continued)



TABLE 4	-1:	CPU C	ORE RE	GISTE	R MAP F	OR dsF	PIC33EP	XXXMC	20X/50X	AND d	sPIC33I	EPXXX	GP50X	DEVICE	S ONL	(CON	TINUE	D)
File Name	Addr.	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	All Resets
SR	0042	OA	OB	SA	SB	OAB	SAB	DA	DC	IPL2	IPL1	IPL0	RA	Ν	OV	Z	С	0000
CORCON	0044	VAR	_	US<	1:0>	EDT		DL<2:0>		SATA	SATB	SATDW	ACCSAT	IPL3	SFA	RND	IF	0020
MODCON	0046	XMODEN	YMODEN	_	_		BWM<3:0> YWM<3:0> XWM<3:0>							0000				
XMODSRT	0048		XMODSRT<15:0>								_	0000						
XMODEND	004A		XMODEND<15:0>									_	0001					
YMODSRT	004C							YMC	DSRT<15:0	>								0000
YMODEND	004E							YMC	DEND<15:0)>								0001
XBREV	0050	BREN							XBF	REV<14:0>								0000
DISICNT	0052	_	_							DISICNT<	13:0>							0000
TBLPAG	0054		_	_	_	_	_	_	_				TBLPA	G<7:0>				0000
MSTRPR	0058								MSTRPR<	:15:0>								0000

Legend: x = unknown value on Reset, - = unimplemented, read as '0'. Reset values are shown in hexadecimal.

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TABLE 4-64: BIT-REVERSED ADDRESSING SEQUENCE (16-ENTRY)

		Norma	al Addre	SS	Bit-Reversed Address					
A3	A2	A1	A0	Decimal	A3	A2	A1	A0	Decimal	
0	0	0	0	0	0	0	0	0	0	
0	0	0	1	1	1	0	0	0	8	
0	0	1	0	2	0	1	0	0	4	
0	0	1	1	3	1	1	0	0	12	
0	1	0	0	4	0	0	1	0	2	
0	1	0	1	5	1	0	1	0	10	
0	1	1	0	6	0	1	1	0	6	
0	1	1	1	7	1	1	1	0	14	
1	0	0	0	8	0	0	0	1	1	
1	0	0	1	9	1	0	0	1	9	
1	0	1	0	10	0	1	0	1	5	
1	0	1	1	11	1	1	0	1	13	
1	1	0	0	12	0	0	1	1	3	
1	1	0	1	13	1	0	1	1	11	
1	1	1	0	14	0	1	1	1	7	
1	1	1	1	15	1	1	1	1	15	

5.2 RTSP Operation

RTSP allows the user application to erase a single page of memory and to program two instruction words at a time. See the General Purpose and Motor Control Family tables (Table 1 and Table 2, respectively) for the page sizes of each device.

For more information on erasing and programming Flash memory, refer to "Flash Programming" (DS70609) in the "dsPIC33/PIC24 Family Reference Manual".

5.3 **Programming Operations**

A complete programming sequence is necessary for programming or erasing the internal Flash in RTSP mode. The processor stalls (waits) until the programming operation is finished.

For erase and program times, refer to Parameters D137a and D137b (Page Erase Time), and D138a and D138b (Word Write Cycle Time) in Table 30-14 in **Section 30.0 "Electrical Characteristics"**.

Setting the WR bit (NVMCON<15>) starts the operation and the WR bit is automatically cleared when the operation is finished.

5.3.1 PROGRAMMING ALGORITHM FOR FLASH PROGRAM MEMORY

Programmers can program two adjacent words (24 bits x 2) of program Flash memory at a time on every other word address boundary (0x000002, 0x000006, 0x00000A, etc.). To do this, it is necessary to erase the page that contains the desired address of the location the user wants to change.

For protection against accidental operations, the write initiate sequence for NVMKEY must be used to allow any erase or program operation to proceed. After the programming command has been executed, the user application must wait for the programming time until programming is complete. The two instructions following the start of the programming sequence should be NOPS.

Refer to **Flash Programming**" (DS70609) in the "*dsPIC33/PIC24 Family Reference Manual*" for details and codes examples on programming using RTSP.

5.4 Flash Memory Resources

Many useful resources are provided on the main product page of the Microchip web site for the devices listed in this data sheet. This product page, which can be accessed using this link, contains the latest updates and additional information.

Note:	In the event you are not able to access the
	product page using the link above, enter
	this URL in your browser:
	http://www.microchip.com/wwwproducts/
	Devices.aspx?dDocName=en555464

5.4.1 KEY RESOURCES

- "Flash Programming" (DS70609) in the "dsPIC33/PIC24 Family Reference Manual"
- Code Samples
- Application Notes
- Software Libraries
- Webinars
- All Related "dsPIC33/PIC24 Family Reference Manual" Sections
- Development Tools

5.5 Control Registers

Four SFRs are used to erase and write the program Flash memory: NVMCON, NVMKEY, NVMADRH and NVMADRL.

The NVMCON register (Register 5-1) enables and initiates Flash memory erase and write operations.

NVMKEY (Register 5-4) is a write-only register that is used for write protection. To start a programming or erase sequence, the user application must consecutively write 0x55 and 0xAA to the NVMKEY register.

There are two NVM Address registers: NVMADRH and NVMADRL. These two registers, when concatenated, form the 24-bit Effective Address (EA) of the selected word for programming operations or the selected page for erase operations.

The NVMADRH register is used to hold the upper 8 bits of the EA, while the NVMADRL register is used to hold the lower 16 bits of the EA.

REGISTER 8-7: DMAXPAD: DMA CHANNEL X PERIPHERAL ADDRESS REGISTER⁽¹⁾

R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0				
			PAD	<15:8>							
bit 15							bit 8				
R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0				
	PAD<7:0>										
bit 7							bit 0				
Legend:											
R = Readable bit W = Writable bit			oit	U = Unimplemented bit, read as '0'							
-n = Value at P	OR	'1' = Bit is set		'0' = Bit is cle	ared	x = Bit is unkr	nown				

bit 15-0 PAD<15:0>: Peripheral Address Register bits

Note 1: If the channel is enabled (i.e., active), writes to this register may result in unpredictable behavior of the DMA channel and should be avoided.

REGISTER 8-8: DMAXCNT: DMA CHANNEL X TRANSFER COUNT REGISTER⁽¹⁾

U-0	U-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0			
	_			CNT<	13:8> (2)					
bit 15							bit 8			
R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0			
CNT<7:0> ⁽²⁾										
bit 7							bit 0			
Legend:										
R = Readable bit W = Writable bit			oit	U = Unimplemented bit, read as '0'						
-n = Value at P	OR	'1' = Bit is set		'0' = Bit is cle	ared	x = Bit is unknown				

bit 15-14 Unimplemented: Read as '0'

bit 13-0 CNT<13:0>: DMA Transfer Count Register bits⁽²⁾

Note 1: If the channel is enabled (i.e., active), writes to this register may result in unpredictable behavior of the DMA channel and should be avoided.

2: The number of DMA transfers = CNT<13:0> + 1.

dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/50X AND PIC24EPXXXGP/MC20X

U-0	U-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0				
	—			RP57	R<5:0>						
bit 15							bit 8				
U-0	U-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0				
	—			RP56	R<5:0>						
bit 7							bit 0				
Legend:											
R = Readab	le bit	W = Writable	bit	U = Unimplem	nented bit, rea	d as '0'					
-n = Value a	t POR	'1' = Bit is set	t	'0' = Bit is clea	ared	x = Bit is unkr	nown				
bit 15-14	Unimpleme	nted: Read as '	0'								
bit 13-8	RP57R<5:0> (see Table 1 [*]	RP57R<5:0>: Peripheral Output Function is Assigned to RP57 Output Pin bits (see Table 11-3 for peripheral function numbers)									
bit 7-6	Unimpleme	Unimplemented: Read as '0'									

REGISTER 11-24: RPOR6: PERIPHERAL PIN SELECT OUTPUT REGISTER 6

(see Table	11-3 for peripheral function numbers)	

REGISTER 11-25: RPOR7: PERIPHERAL PIN SELECT OUTPUT REGISTER 7

U-0	U-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0		
—	—		RP97R<5:0>						
bit 15							bit 8		

RP56R<5:0>: Peripheral Output Function is Assigned to RP56 Output Pin bits

U-0	U-0	U-0	U-0	U-0	U-0	U-0	U-0
—	—	—	—	—	—	—	—
bit 7							bit 0

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented bit, read	l as '0'
-n = Value at POR	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

bit 15-14 Unimplemented: Read as '0'

bit 13-8 **RP97R<5:0>:** Peripheral Output Function is Assigned to RP97 Output Pin bits (see Table 11-3 for peripheral function numbers)

bit 7-0 Unimplemented: Read as '0'

bit 5-0

dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/50X AND PIC24EPXXXGP/MC20X

REGISTER 16-8: PDCx: PWMx GENERATOR DUTY CYCLE REGISTER

R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0				
			PDC	x<15:8>							
bit 15							bit 8				
R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0				
	PDCx<7:0>										
bit 7							bit 0				
Legend:											
R = Readable bit W = Writable bit				U = Unimplemented bit, read as '0'							
-n = Value at POR '1' = Bit is set '0' = Bit is cleared					x = Bit is unkr	nown					

bit 15-0 **PDCx<15:0>:** PWMx Generator # Duty Cycle Value bits

REGISTER 16-9: PHASEx: PWMx PRIMARY PHASE-SHIFT REGISTER

R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
			PHAS	Ex<15:8>			
bit 15							bit 8
R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
			PHAS	SEx<7:0>			
bit 7							bit 0
Legend:							
R = Readable I	bit	W = Writable b	it	U = Unimpler	mented bit, rea	ad as '0'	
-n = Value at P	OR	'1' = Bit is set		'0' = Bit is cle	ared	x = Bit is unkı	nown

bit 15-0 PHASEx<15:0>: PWMx Phase-Shift Value or Independent Time Base Period for the PWM Generator bits

Note 1: If ITB (PWMCONx<9>) = 0, the following applies based on the mode of operation: Complementary, Redundant and Push-Pull Output mode (PMOD<1:0> (IOCON<11:10>) = 00, 01 or 10), PHASEx<15:0> = Phase-shift value for PWMxH and PWMxL outputs

 If ITB (PWMCONx<9>) = 1, the following applies based on the mode of operation: Complementary, Redundant and Push-Pull Output mode (PMOD<1:0> (IOCONx<11:10>) = 00, 01 or 10), PHASEx<15:0> = Independent time base period value for PWMxH and PWMxL

R/W-0	R/W-0	R/W-0	R/W-0	U-0	U-0	U-0	U-0
	TRGDI	V<3:0>		—	—	—	—
bit 15							bit 8
U-0	U-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
—	—			TRGSTF	RT<5:0>(1)		
bit 7							bit 0
Legend:							
R = Readable	e bit	W = Writable	bit	U = Unimplen	nented bit, read	as '0'	
-n = Value at	POR	'1' = Bit is set		'0' = Bit is clea	ared	x = Bit is unkn	own
bit 15-12	TRGDIV<3:0)>: Trigger # Ou	tput Divider b	vits			
	1111 = Trigg	er output for ev	ery 16th trigg	er event			
	1110 = Trigg	er output for ev	ery 15th trigg	er event			
	1101 = Trigg	er output for ev	ery 14th trigg	er event			
	1100 = Trigg	er output for ev	ery 13th trigg	er event			
	1011 = Irigg	er output for ev	ery 12th trigg	er event			
	1010 = Trigg	per output for ev	ery 11th trigge	er event			
	1001 - Trigg	er output for ev	ery 9th triage	r event			
	0111 = Trigg	er output for ev	erv 8th triage	r event			
	0110 = Trigg	er output for ev	erv 7th triage	r event			
	0101 = Trigg	er output for ev	ery 6th trigge	r event			
	0100 = Trigg	jer output for ev	ery 5th trigge	r event			
	0011 = Trigg	er output for ev	ery 4th trigge	r event			
	0010 = Trigg	er output for ev	ery 3rd trigge	r event			
	0001 = Trigg	er output for ev	ery 2nd trigge	erevent			
	0000 = Trigg	ger output for ev	ery trigger ev	ent			
bit 11-6	Unimplemer	nted: Read as '	0'				
bit 5-0	TRGSTRT<5	5:0>: Trigger Po	stscaler Start	Enable Select	bits ⁽¹⁾		
	111111 = W	aits 63 PWM cy	cles before g	enerating the fir	rst trigger event	after the modu	le is enabled
	•						
	•						
	•						
	000010 = W	aits 2 PWM cyc	les before ge	nerating the firs	t trigger event a	after the module	e is enabled
	000001 = W	aits 1 PWM cyc	le before gen	erating the first	trigger event a	fter the module	is enabled
	000000 = W	aits 0 PWM cyc	les before ge	nerating the firs	t trigger event	after the module	e is enabled

REGISTER 16-12: TRGCONx: PWMx TRIGGER CONTROL REGISTER





dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/50X AND PIC24EPXXXGP/MC20X

dsPIC33EPXXXGP50X, dsPIC33EPXXXMC20X/50X AND PIC24EPXXXGP/MC20X

R/W-0	U-0	U-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
ADRC	—	—	SAMC4 ⁽¹⁾	SAMC3 ⁽¹⁾	SAMC2 ⁽¹⁾	SAMC1 ⁽¹⁾	SAMC0 ⁽¹⁾
bit 15							bit 8
R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
ADCS7(2	²⁾ ADCS6 ⁽²⁾	ADCS5 ⁽²⁾	ADCS4 ⁽²⁾	ADCS3 ⁽²⁾	ADCS2 ⁽²⁾	ADCS1 ⁽²⁾	ADCS0 ⁽²⁾
bit 7							bit 0
Legend:							
R = Reada		vv = vvritable t	DIT		nented bit, read		
-n = value	at POR	"1" = Bit is set		$0^{\circ} = Bit is cle$	ared	x = Bit is unkr	nown
bit 15	bit 15 ADRC: ADC1 Conversion Clock Source bit 1 = ADC internal RC clock 0 = Clock derived from system clock						
bit 14-13	Unimplement	ted: Read as '0	3				
bit 12-8	SAMC<4:0>:	Auto-Sample T	ime bits ⁽¹⁾				
	11111 = 31 TAD						
hit 7 0	00000 = 0 IA		ion Clock Colo	at hita(2)			
DIT 7-0 ADCS<7:0>: ADC1 Conversion Clock Select Dits ⁽²⁾ 11111111 = TP • (ADCS<7:0> + 1) = TP • 256 = TAD • • • • • • • • • • • • •							
Note 1: 2:	This bit is only use This bit is not used	d if SSRC<2:0> if ADRC (AD10	· (AD1CON1< CON3<15>) =	7:5>) = 111 ar 1.	nd SSRCG (AD	1CON1<4>) =	0.

REGISTER 23-3: AD1CON3: ADC1 CONTROL REGISTER 3

R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
CSS15	CSS14	CSS13	CSS12	CSS11	CSS10	CSS9	CSS8
bit 15							bit 8
R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
CSS7	CSS6	CSS5	CSS4	CSS3	CSS2	CSS1	CSS0
bit 7	·						bit 0
Legend:							
R = Readable	bit	W = Writable b	oit	U = Unimplei	mented bit, read	d as '0'	
-n = Value at F	POR	'1' = Bit is set		'0' = Bit is cle	ared	x = Bit is unkr	nown

REGISTER 23-8: AD1CSSL: ADC1 INPUT SCAN SELECT REGISTER LOW^(1,2)

bit 15-0 CSS<15:0>: ADC1 Input Scan Selection bits

1 = Selects ANx for input scan

0 = Skips ANx for input scan

Note 1: On devices with less than 16 analog inputs, all AD1CSSL bits can be selected by the user. However, inputs selected for scan, without a corresponding input on the device, convert VREFL.

2: CSSx = ANx, where x = 0-15.

25.3 Op Amp/Comparator Registers

R/W-0	U-0	U-0	U-0	R-0	R-0	R-0	R-0
PSIDL				C4EVT ⁽¹⁾	C3EVT ⁽¹⁾	C2EVT ⁽¹⁾	C1EVT ⁽¹⁾
bit 15	1			1			bit 8
U-0	U-0	U-0	U-0	R-0	R-0	R-0	R-0
		—		C4OUT ⁽²⁾	C3OUT ⁽²⁾	C2OUT ⁽²⁾	C1OUT ⁽²⁾
bit 7							bit 0
r							
Legend:							
R = Readable	bit	W = Writable	bit	U = Unimpler	nented bit, read	l as '0'	
-n = Value at F	POR	'1' = Bit is set		0' = Bit is cle	ared	x = Bit is unkn	iown
hit 15		arator Stop in	dla Mada hit				
DIL 15	1 = Discontinu	ues operation of	of all comparat	ors when devi	ce enters Idle n	node	
	0 = Continues	s operation of a	Il comparators	s in Idle mode		1000	
bit 14-12	Unimplement	ted: Read as ')'				
bit 11	C4EVT: Op A	mp/Comparato	r 4 Event Stat	us bit ⁽¹⁾			
	1 = Op amp/c	omparator eve	nt occurred				
L:1 40	0 = Op amp/c	omparator eve		Jr			
DIT 10	1 = Comparat	corator 3 Even	Status Dit				
	0 = Comparat	or event did no	ot occur				
bit 9	C2EVT: Comp	parator 2 Event	: Status bit ⁽¹⁾				
	1 = Comparat	or event occur	red				
	0 = Comparat	or event did no	ot occur				
bit 8	C1EVT: Comp	parator 1 Event	Status bit ⁽¹⁾				
	1 = Comparat	or event occur	red of occur				
bit 7-4	Unimplement	ted: Read as ')'				
bit 3	C4OUT: Com	parator 4 Outp	ut Status bit ⁽²⁾				
	When CPOL =	= 0:					
	1 = VIN + > VIN	N-					
	0 = VIN + < VIN	N- - 1·					
	1 = VIN + < VIN	<u></u> N-					
	0 = VIN + > VIN	N-					
bit 2	C3OUT: Comparator 3 Output Status bit ⁽²⁾						
	$\frac{\text{When CPOL} = 0}{1 - 1}$						
	1 = VIN + > VIN $0 = VIN + < VIN$	N- N-					
	When CPOL =	= 1:					
	$1 = VIN + \langle VIN - VIN $						
	$\cup = VIN + > VIN$	N-					

REGISTER 25-1: CMSTAT: OP AMP/COMPARATOR STATUS REGISTER

- **Note 1:** Reflects the value of the of the CEVT bit in the respective Op Amp/Comparator Control register, CMxCON<9>.
 - 2: Reflects the value of the COUT bit in the respective Op Amp/Comparator Control register, CMxCON<8>.

REGISTER 25-4: CMxMSKSRC: COMPARATOR x MASK SOURCE SELECT CONTROL REGISTER (CONTINUED)

- bit 3-0 SELSRCA<3:0>: Mask A Input Select bits
 - 1111 = FLT4 1110 = FLT2 1101 = PTGO19 1100 = PTGO18 1011 = Reserved 1010 = Reserved 1001 = Reserved 1000 = Reserved 0111 = Reserved 0110 = Reserved 0101 = PWM3H 0100 = PWM3L 0011 = PWM2H 0010 = PWM2L 0001 = PWM1H 0000 = PWM1L

U-0	U-0	U-0	U-0	U-0	U-0	U-0	U-0
	_				—		
bit 15							bit 8
U-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0
	CFSEL2	CFSEL1	CFSEL0	CFLTREN	CFDIV2	CFDIV1	CFDIV0
bit 7							bit 0
Logondi							
R = Reada	able hit	W = Writable	hit	= Inimpler	mented hit read	ae 'O'	
-n = Value	at POR	(1) = Rit is set	bit	'0' = Bit is cle	ared	x = Rit is unkr	nown
II Value		1 Bit lo oot					lowin
bit 15-7	Unimplemen	nted: Read as '	0'				
bit 6-4	CFSEL<2:0>	Comparator I	-ilter Input Clo	ck Select bits			
	111 = T5CLK	(1) (1)					
	110 = T4CLK	< ⁽²⁾					
	101 = T3CLK	<(1) <(2)					
	100 = 12CLP	ved					
	010 = SYNC	01 ⁽³⁾					
	001 = Fosc ⁽⁴	4)					
	000 = FP ⁽⁴⁾						
bit 3	CFLTREN: C	Comparator Filte	er Enable bit				
	1 = Digital filt	er is enabled					
hit 2-0		Comparator F	ilter Clock Div	ide Select hits			
511 2-0	111 = Clock	Divide 1.128					
	110 = Clock	Divide 1:64					
	101 = Clock	101 = Clock Divide 1:32					
	100 = Clock	100 = Clock Divide 1:16					
	011 = Clock	011 = Clock Divide 1:8					
	001 = Clock	Divide 1:2					
	000 = Clock	Divide 1:1					
Note 1:	See the Type C Ti	mer Block Diac	ram (Figure 1	3-2).			
2:	See the Type B Timer Block Diagram (Figure 13-1).						

REGISTER 25-6: CMxFLTR: COMPARATOR x FILTER CONTROL REGISTER

- 3: See the High-Speed PWMx Module Register Interconnection Diagram (Figure 16-2).
 - 4: See the Oscillator System Diagram (Figure 9-1).

DC CHARACTERISTICS			Standard Opera (unless otherw Operating temp	ating Conditions: 3.0V to ise stated) erature $-40^{\circ}C \le TA \le +8$ $-40^{\circ}C < TA < +1$	3.6V 5°C for Industrial 25°C for Extended	
Parameter No.	Тур.	Max.	Units	Units Conditions		
Power-Down	Current (IPD) ⁽¹⁾ -	dsPIC33EP32GI	P50X, dsPIC33EI	P32MC20X/50X and PIC	24EP32GP/MC20X	
DC60d	30	100	μΑ	-40°C		
DC60a	35	100	μΑ	+25°C	2 2)/	
DC60b	150	200	μΑ	+85°C	3.3V	
DC60c	250	500	μA	+125°C		
Power-Down	Current (IPD) ⁽¹⁾ -	dsPIC33EP64GI	P50X, dsPIC33EI	P64MC20X/50X and PIC	24EP64GP/MC20X	
DC60d	25	100	μA	-40°C		
DC60a	30	100	μA	+25°C	2.21/	
DC60b	150	350	μΑ	+85°C	3.3V	
DC60c	350	800	μΑ	+125°C		
Power-Down	Current (IPD) ⁽¹⁾ –	dsPIC33EP128G	P50X, dsPIC33E	P128MC20X/50X and Pl	C24EP128GP/MC20X	
DC60d	30	100	μΑ	-40°C		
DC60a	35	100	μΑ	+25°C	3 3//	
DC60b	150	350	μΑ	+85°C	5.50	
DC60c	550	1000	μΑ	+125°C		
Power-Down	Current (IPD) ⁽¹⁾ –	dsPIC33EP256G	P50X, dsPIC33E	P256MC20X/50X and Pl	C24EP256GP/MC20X	
DC60d	35	100	μA	-40°C		
DC60a	40	100	μA	+25°C	3 3//	
DC60b	250	450	μΑ	+85°C	5.5 V	
DC60c	1000	1200	μΑ	+125°C		
Power-Down	Current (IPD) ⁽¹⁾ –	dsPIC33EP512G	P50X, dsPIC33E	P512MC20X/50X and Plo	C24EP512GP/MC20X	
DC60d	40	100	μA	-40°C		
DC60a	45	100	μΑ	+25°C	3 3\/	
DC60b	350	800	μΑ	+85°C	3.3V	
DC60c	1100	1500	μΑ	+125°C		

TABLE 30-8: DC CHARACTERISTICS: POWER-DOWN CURRENT (IPD)

Note 1: IPD (Sleep) current is measured as follows:

• CPU core is off, oscillator is configured in EC mode and external clock is active; OSC1 is driven with external square wave from rail-to-rail (EC clock overshoot/undershoot < 250 mV required)

- · CLKO is configured as an I/O input pin in the Configuration Word
- All I/O pins are configured as inputs and pulled to Vss
- MCLR = VDD, WDT and FSCM are disabled
- All peripheral modules are disabled (PMDx bits are all set)
- The VREGS bit (RCON<8>) = 0 (i.e., core regulator is set to standby while the device is in Sleep mode)
- The VREGSF bit (RCON<11>) = 0 (i.e., Flash regulator is set to standby while the device is in Sleep mode)
- JTAG is disabled

TABLE 30-38:SPI2 SLAVE MODE (FULL-DUPLEX, CKE = 1, CKP = 1, SMP = 0)TIMING REQUIREMENTS

АС СНА	AC CHARACTERISTICS		Standard Operating Conditions: 3.0V to 3.6V(unless otherwise stated)Operating temperature $-40^{\circ}C \le TA \le +85^{\circ}C$ for Industrial $-40^{\circ}C < TA \le +125^{\circ}C$ for Extended				
Param.	Symbol	Characteristic ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units	Conditions
SP70	FscP	Maximum SCK2 Input Frequency	_		Lesser of FP or 11	MHz	(Note 3)
SP72	TscF	SCK2 Input Fall Time	—	_	_	ns	See Parameter DO32 (Note 4)
SP73	TscR	SCK2 Input Rise Time	—	_	_	ns	See Parameter DO31 (Note 4)
SP30	TdoF	SDO2 Data Output Fall Time	—			ns	See Parameter DO32 (Note 4)
SP31	TdoR	SDO2 Data Output Rise Time	—			ns	See Parameter DO31 (Note 4)
SP35	TscH2doV, TscL2doV	SDO2 Data Output Valid after SCK2 Edge	—	6	20	ns	
SP36	TdoV2scH, TdoV2scL	SDO2 Data Output Setup to First SCK2 Edge	30	_	_	ns	
SP40	TdiV2scH, TdiV2scL	Setup Time of SDI2 Data Input to SCK2 Edge	30			ns	
SP41	TscH2diL, TscL2diL	Hold Time of SDI2 Data Input to SCK2 Edge	30	_	_	ns	
SP50	TssL2scH, TssL2scL	SS2 ↓ to SCK2 ↑ or SCK2 ↓ Input	120	_	-	ns	
SP51	TssH2doZ	SS2 ↑ to SDO2 Output High-Impedance	10	_	50	ns	(Note 4)
SP52	TscH2ssH TscL2ssH	SS2 ↑ after SCK2 Edge	1.5 TCY + 40	_	_	ns	(Note 4)
SP60	TssL2doV	SDO2 Data Output Valid after SS2 Edge	—	_	50	ns	

Note 1: These parameters are characterized, but are not tested in manufacturing.

2: Data in "Typical" column is at 3.3V, +25°C unless otherwise stated.

3: The minimum clock period for SCK2 is 91 ns. Therefore, the SCK2 clock generated by the master must not violate this specification.

4: Assumes 50 pF load on all SPI2 pins.

DC CHARACTERISTICS			$\begin{array}{l} \mbox{Standard Operating Conditions:} 3.0V \ to \ 3.6V \\ \mbox{(unless otherwise stated)} \\ \mbox{Operating temperature} & -40^{\circ}C \leq TA \leq +85^{\circ}C \ for \ Industrial \\ & -40^{\circ}C \leq TA \leq +125^{\circ}C \ for \ Extended \end{array}$				
Param No.	Symbol	Characteristic	Min.	Тур.	Max.	Units	Conditions
CTMU Curr	rent Source	9					
CTMUI1	IOUT1	Base Range ⁽¹⁾	0.29	_	0.77	μA	CTMUICON<9:8> = 01
CTMUI2	IOUT2	10x Range ⁽¹⁾	3.85	—	7.7	μA	CTMUICON<9:8> = 10
CTMUI3	IOUT3	100x Range ⁽¹⁾	38.5	—	77	μA	CTMUICON<9:8> = 11
CTMUI4	IOUT4	1000x Range ⁽¹⁾	385	—	770	μA	CTMUICON<9:8> = 00
CTMUFV1	VF	Temperature Diode Forward Voltage ^(1,2)	_	0.598		V	TA = +25°C, CTMUICON<9:8> = 01
			-	0.658		V	TA = +25°C, CTMUICON<9:8> = 10
			-	0.721		V	TA = +25°C, CTMUICON<9:8> = 11
CTMUFV2	VFVR	Temperature Diode Rate of	_	-1.92	_	mV/ºC	CTMUICON<9:8> = 01
		Change ^(1,2,3)	_	-1.74	_	mV/ºC	CTMUICON<9:8> = 10
			_	-1.56	_	mV/ºC	CTMUICON<9:8> = 11

TABLE 30-56: CTMU CURRENT SOURCE SPECIFICATIONS

Note 1: Nominal value at center point of current trim range (CTMUICON<15:10> = 000000).

2: Parameters are characterized but not tested in manufacturing.

3: Measurements taken with the following conditions:

- VREF+ = AVDD = 3.3V
- ADC configured for 10-bit mode
- ADC module configured for conversion speed of 500 ksps
- All PMDx bits are cleared (PMDx = 0)
- Executing a while(1) statement
- · Device operating from the FRC with no PLL

28-Lead Plastic Shrink Small Outline (SS) - 5.30 mm Body [SSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	E		0.65 BSC	
Contact Pad Spacing	С		7.20	
Contact Pad Width (X28)	X1			0.45
Contact Pad Length (X28)	Y1			1.75
Distance Between Pads	G	0.20		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2073A

Revision E (April 2012)

This revision includes typographical and formatting changes throughout the data sheet text.

All other major changes are referenced by their respective section in Table A-3.

TABLE A-4:	MAJOR SECTION UPDATES
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Section Name	Update Description
"16-bit Microcontrollers and Digital Signal Controllers (up to 512-Kbyte Flash and 48-Kbyte SRAM) with High- Speed PWM, Op amps, and Advanced Analog"	The following 512-Kbyte devices were added to the General Purpose Families table (see Table 1): PIC24EP512GP202 PIC24EP512GP204 PIC24EP512GP206 dsPIC33EP512GP502 dsPIC33EP512GP506 The following 512-Kbyte devices were added to the Motor Control Families table (see Table 2): PIC24EP512MC202 PIC24EP512MC204 PIC24EP512MC206 dsPIC33EP512MC202 dsPIC33EP512MC202 dsPIC33EP512MC204 dsPIC33EP512MC204 dsPIC33EP512MC206 dsPIC33EP512MC206 dsPIC33EP512MC506
Section 4.0 "Memory Organization"	Added a Program Memory Map for the new 512-Kbyte devices (see Figure 4-4). Added a Data Memory Map for the new dsPIC 512-Kbyte devices (see Figure 4-11). Added a Data Memory Map for the new PIC24 512-Kbyte devices (see Figure 4-16).
Section 7.0 "Interrupt Controller"	Updated the VECNUM bits in the INTTREG register (see Register 7-7).
Section 11.0 "I/O Ports"	Added tip 6 to Section 11.5 "I/O Helpful Tips".
Section 27.0 "Special Features"	 The following modifications were made to the Configuration Byte Register Map (see Table 27-1): Added the column Device Memory Size (Kbytes) Removed Notes 1 through 4 Added addresses for the new 512-Kbyte devices
Section 30.0 "Electrical Characteristics"	Updated the Minimum value for Parameter DC10 (see Table 30-4). Added Power-Down Current (Ipd) parameters for the new 512-Kbyte devices (see Table 30-8). Updated the Minimum value for Parameter CM34 (see Table 30-53). Updated the Minimum and Maximum values and the Conditions for parameter SY12 (see Table 30-22).